Temperature-sensing luminescent materials La_{9.67}Si₆O_{26.5}:Yb³⁺-Er³⁺/Ho³⁺

based on pump-power-dependent upconversion luminescence

Jia Zhang^{1,2,*}, Jiajun Chen¹, Yining Zhang¹

¹Physics department and Jiangsu Key Laboratory of Modern Measurement

Technology and Intelligence, Huaiyin Normal University, 111 West Chang Jiang

Road, Huai'an 223300, China

²Jiangsu Key Laboratory for Chemistry of Low-Dimensional Materials, Huaiyin

Normal University, 111 West Chang Jiang Road, Huai'an 223300, China

*Corresponding author.

E-mail address: zhangjianew@126.com



Figure S1 (a) Excitation spectrum of LSO:10%Yb³⁺,1%Er³⁺ monitored by 553 nm; (b) emission spectra of LSO:10%Yb³⁺,xHo³⁺ (1% $\leq x \leq$ 3%) upon 377 nm excitation



Figure S2 (a) Excitation spectrum of LSO:10%Yb³⁺,1%Ho³⁺ monitored by 544 nm; (b) emission spectra of LSO:10%Yb³⁺,yHo³⁺ (1% $\leq y \leq$ 3%) upon 450 nm excitation; (c) normalized (for 544 nm) emission spectra of LSO:10%Yb³⁺,1%Ho³⁺ excited by CW

and pulse light source of 980 nm



Figure S3 Emission spectra of LSO:10%Yb³⁺,1%Er³⁺ excited at 980 nm excitation

under various pump powers; (b) dependences of ln*I* for 522, 553 and 657 nm

emissions of Er^{3+} on lnP



Figure S4 Emission spectra of LSO:10%Yb³⁺,1%Ho³⁺ excited at 980 nm excitation under various pump powers; (b) dependences of ln*I* for 545 and 657 nm emissions of

 Ho^{3+} on $\mathrm{ln}P$



Figure S5 Normalized emission spectra of LSO:10%Yb³⁺,1%Er³⁺ excited under various temperatures for the pump power of (a) 249 mW, (b) 800 mW and (c) 1490

mW



Figure S6 (a) Emission spectra of LSO:10%Yb³⁺,1%Er³⁺ excited at 377 nm under various temperatures; (b) relative intensities of 521 and 553 nm emissions of Er³⁺ as a

function of temperature; (c) dependence of I_{521}/I_{553} on absolute temperature



Figure S7 Dependences of I_{521}/I_{553} on absolute temperature for LSO:10%Yb³⁺,1%Er³⁺ excited under the pump power of (a) 800 mW and (b) 1490 mW



Figure S8 Emission spectra of LSO:10%Yb³⁺,1%Er³⁺ by repeating the measurement

excited by 980 nm of 249 mW under various temperatures



Figure S9 Dependences of I₅₂₁/I₅₅₃ on absolute temperature for repeating measurement,

inset shows the δT value as a function of temperature



Figure S10 (a) Decay curves of LSO:10%Yb³⁺,1%Er³⁺ excited at 980 nm and

monitored at 553 nm; (b) dependence of decay lifetime on temperature